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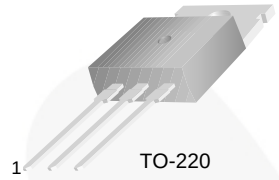
November 2014

FJP13007
High Voltage Fast-Switching NPN Power Transistor

Features

- High Voltage High Speed Power Switch Application
- High Voltage Capability
- High Switching Speed
- Suitable for Electronic Ballast and Switching Mode Power Supply



TO-220

1.Base 2.Collector 3.Emitter

Ordering Information

Part Number	Top Mark	Package	Packing Method
FJP13007TU	J13007	TO-220 3L (Dual Gauge)	Rail
FJP13007H1TU	J13007-1	TO-220 3L (Single Gauge)	Rail
FJP13007H1TU_F080	J13007-1	TO-220 3L (Dual Gauge)	Rail
FJP13007H2TU	J13007-2	TO-220 3L (Dual Gauge)	Rail
FJP13007H2TU_F080	J13007-2	TO-220 3L (Dual Gauge)	Rail

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at T_C = 25°C unless otherwise noted.

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	700	V
V_{CEO}	Collector-Emitter Voltage	400	V
V_{EBO}	Emitter-Base Voltage	9	V
I_C	Collector Current (DC)	8	A
I_{CP}	Collector Current (Pulse)	16	A
I_B	Base Current (DC)	4	A
P_C	Collector Dissipation (T_C = 25°C)	80	W
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature Range	-65 to 150	°C

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Electrical Characteristics

Values are at T_C = 25°C unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
BV_{CEO}	Collector-Emitter Breakdown Voltage	I_C = 10 mA, I_B = 0	400			V
I_{EBO}	Emitter Cut-Off Current	V_{EB} = 9 V, I_C = 0			1	mA
$h_{FE}1$	DC Current Gain(1)	V_{CE} = 5 V, I_C = 2 A	8		60	
$h_{FE}2$	DC Current Gain(1)	V_{CE} = 5 V, I_C = 5 A	5		30	
V_{CE}(sat)	Collector-Emitter Saturation Voltage	I_C = 2 A, I_B = 0.4 A			1.0	V
		I_C = 5 A, I_B = 1 A			2.0	
		I_C = 8 A, I_B = 2 A			3.0	
V_{BE}(sat)	Collector-Base Saturation Voltage	I_C = 2 A, I_B = 0.4 A			1.2	V
		I_C = 5 A, I_B = 1 A			1.6	
f_T	Current Gain Bandwidth Product	V_{CE} = 10 V, I_C = 0.5 A	4			MHz
C_{ob}	Output Capacitance	V_{CB} = 10 V, f = 0.1 MHz		110		pF
t_{ON}	Turn-On Time	V_{CC} = 125 V, I_C = 5 A, I_{B1} = -I_{B2} = 1 A, R_L = 25 Ω			1.6	µs
t_{STG}	Storage Time				3.0	µs
t_F	Fall Time				0.7	µs

Note:

1. Pulse test: pw ≤ 300 µs, duty cycle ≤ 2%.

h_{FE} Classification

Classification	H1	H2
$h_{FE}1$	15 ~ 28	26 ~ 39

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Typical Performance Characteristics

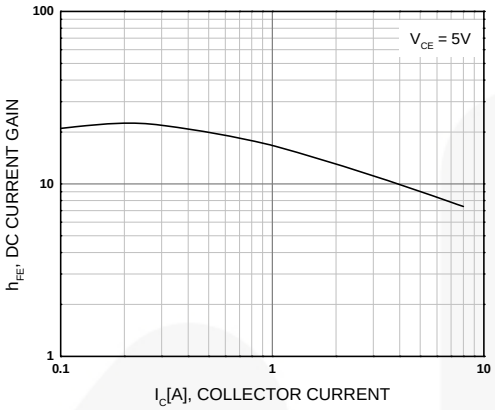

Figure 1. DC Current Gain

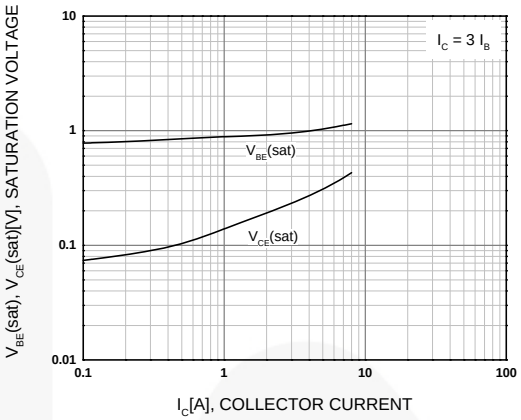

Figure 2. Saturation Voltage

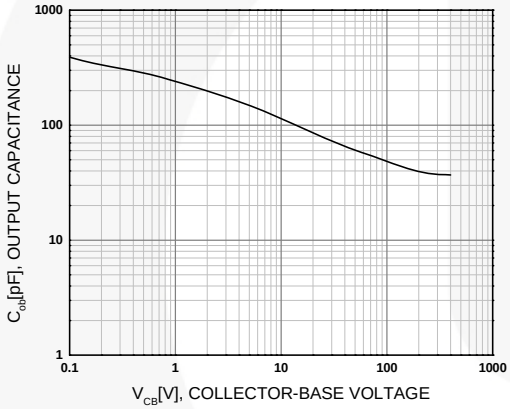

Figure 3. Collector Output Capacitance

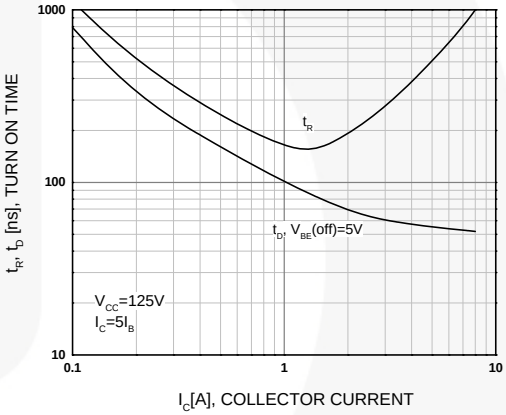

Figure 4. Turn-On Time

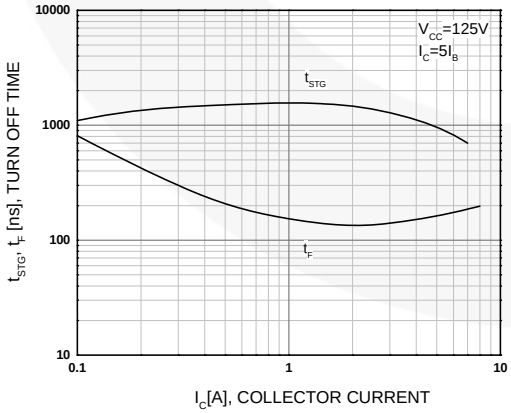

Figure 5. Turn-Off Time

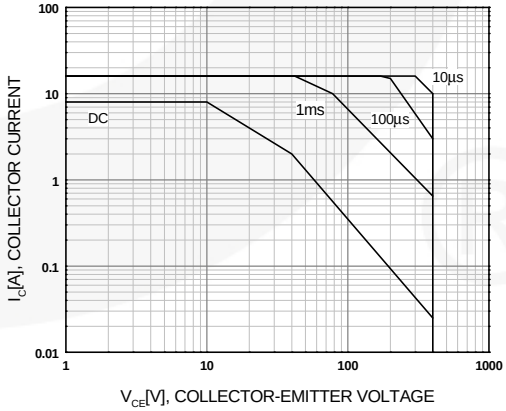

Figure 6. Forward Biased Safe Operating Area

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Typical Performance Characteristics (Continued)

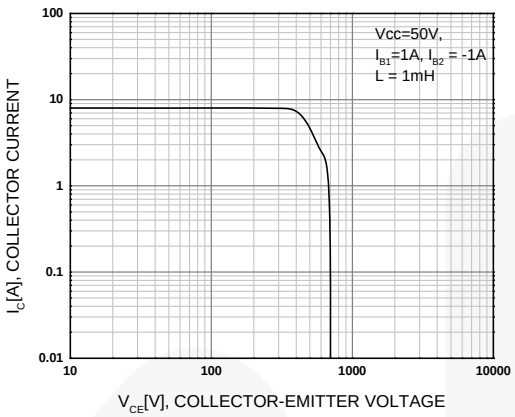

Figure 7. Reverse Biased Safe Operating Area

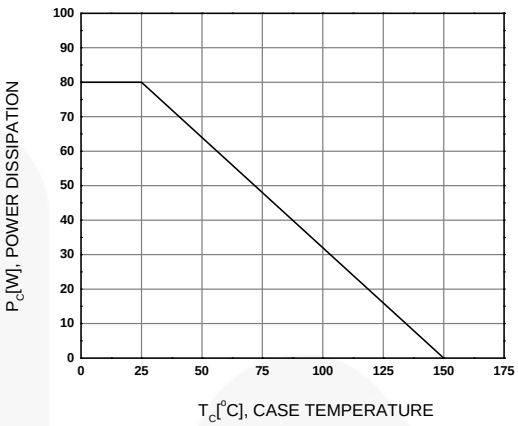

Figure 8. Power Derating

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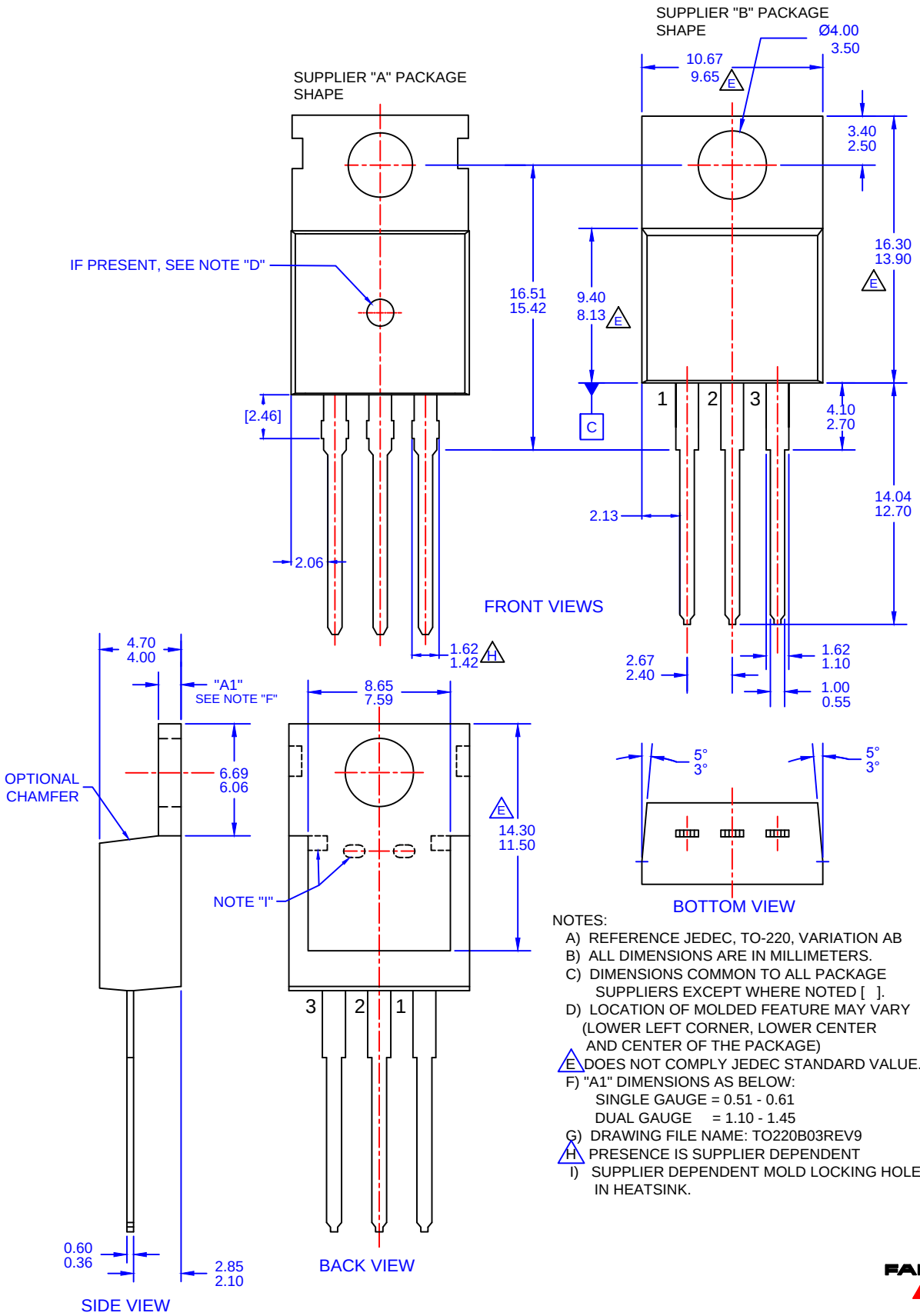

NOTES:

A) REFERENCE JEDEC, TO-220, VARIATION AB
B) ALL DIMENSIONS ARE IN MILLIMETERS.
C) DIMENSIONS COMMON TO ALL PACKAGE SUPPLIERS EXCEPT WHERE NOTED [ ].
D) LOCATION OF MOLDED FEATURE MAY VARY (LOWER LEFT CORNER, LOWER CENTER AND CENTER OF THE PACKAGE)
E DOES NOT COMPLY JEDEC STANDARD VALUE.
F) "A1" DIMENSIONS AS BELOW:
SINGLE GAUGE = 0.51 - 0.61
DUAL GAUGE = 1.10 - 1.45
G) DRAWING FILE NAME: TO220B03REV9
H PRESENCE IS SUPPLIER DEPENDENT
I) SUPPLIER DEPENDENT MOLD LOCKING HOLES IN HEATSINK.

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